

NBSG86A

2.5V/3.3V SiGe Differential Smart Gate with Output Level Select

The NBSG86A is a multi-function differential Logic Gate which can be configured as an AND/NAND, OR/NOR, XOR/XNOR, or 2:1 MUX. This device is part of the GigaComm™ family of high performance Silicon Germanium products. The device is housed in a low profile 4x4 mm, 16-pin, flip-chip LGA or a 3x3 mm 16 pin QFN package.

Differential inputs incorporate internal 50 Ω termination resistors and accept NECL (Negative ECL), PECL (Positive ECL), LVCMOS/LVTTL, CML, or LVDS. The Output Level Select (OLS) input is used to program the peak-to-peak output amplitude between 0 and 800 mV in five discrete steps.

The NBSG86A employs input default circuitry so that under open input conditions (D_x , $\overline{D}_x$, $\overline{VTD}_x$, VTD_x , VTSEL) the outputs of the device will remain stable.

Features

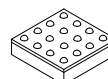
- Maximum Input Clock Frequency > 8 GHz Typical
- Maximum Input Data Rate > 8 Gb/s Typical
- 165 ps Typical Propagation Delay
- 40 ps Typical Rise and Fall Times
- Selectable Swing PECL Output with Operating Range:
 $V_{CC} = 2.375$ V to 3.465 V with $V_{EE} = 0$ V
- Selectable Swing NECL Output with NECL Inputs with
Operating Range: $V_{CC} = 0$ V with $V_{EE} = -2.375$ V to -3.465 V
- Selectable Output Level (0 V, 200 mV, 400 mV, 600 mV, or 800 mV Peak-to-Peak Output)
- 50 Ω Internal Input Termination Resistors
- Pb-Free Packages are Available



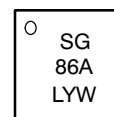
ON Semiconductor®

<http://onsemi.com>

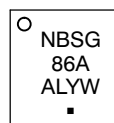
MARKING DIAGRAMS*



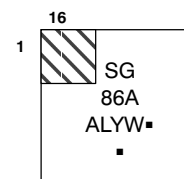
FCBGA-16
BA SUFFIX
CASE 489



FCLGA-16
MA SUFFIX
CASE 526



QFN-16
MN SUFFIX
CASE 485G



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

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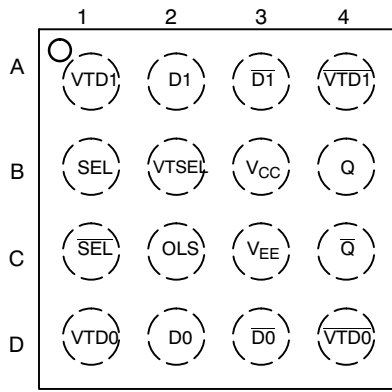


Figure 1. BGA-16 and LGA-16 Pinout (Top View)

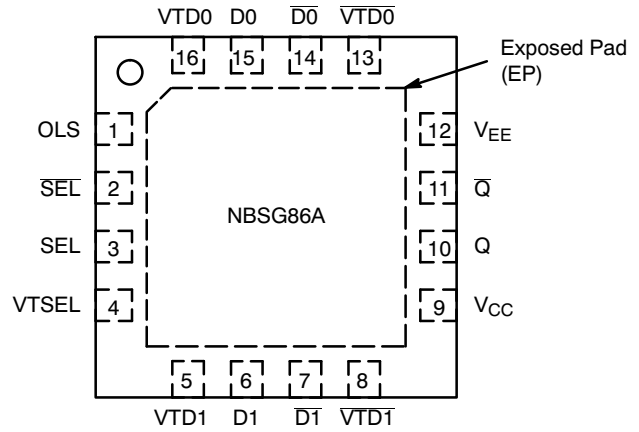


Figure 2. QFN-16 Pinout (Top View)

Table 1. Pin Description

Pin		Name	I/O	Description
BGA	QFN			
C2	1	OLS (Note 3)	Input	Input Pin for the Output Level Select (OLS). See Table 2.
C1	2	$\overline{\text{SEL}}$	ECL, CML, LVCMOS, LVDS, LVTTTL Input	Inverted Differential Select Logic Input.
B1	3	SEL	ECL, CML, LVCMOS, LVDS, LVTTTL Input	Noninverted Differential Select Logic Input.
B2	4	VTSEL	-	Common Internal 50 Ω Termination Pin for SEL/ $\overline{\text{SEL}}$. See Table 7. (Note 1)
A1	5	VTD1	-	Internal 50 Ω termination pin. See Table 7. (Note 1)
A2	6	D1	ECL, CML, LVCMOS, LVDS, LVTTTL Input	Noninverted Differential Input 1. Internal 75 k Ω to V_{EE} .
A3	7	$\overline{\text{D1}}$	ECL, CML, LVCMOS, LVDS, LVTTTL Input	Inverted Differential Input 1. Internal 75 k Ω to V_{EE} and 36.5 k Ω to V_{CC} .
A4	8	$\overline{\text{VTD1}}$	-	Internal 50 Ω Termination Pin. See Table 7. (Note 1)
B3	9	V_{CC}	-	Positive Supply Voltage (Note 2)
B4	10	Q	RSECL Output	Noninverted Differential Output. Typically Terminated with 50 Ω Resistor to $V_{TT} = V_{CC} - 2 \text{ V}$.
C4	11	$\overline{\text{Q}}$	RSECL Output	Inverted Differential Output. Typically Terminated with 50 Ω Resistor to $V_{TT} = V_{CC} - 2 \text{ V}$.
C3	12	V_{EE}	-	Negative Supply Voltage (Note 2)
D4	13	$\overline{\text{VTD0}}$	-	Internal 50 Ω Termination Pin. See Table 7. (Note 1)
D3	14	$\overline{\text{D0}}$	ECL, CML, LVCMOS, LVDS, LVTTTL Input	Inverted Differential Input 0. Internal 75 k Ω to V_{EE} and 36.5 k Ω to V_{CC} .
D2	15	D0	ECL, CML, LVCMOS, LVDS, LVTTTL Input	Noninverted Differential Input 0. Internal 75 k Ω to V_{EE} .
D1	16	VTD0	-	Internal 50 Ω Termination Pin. See Table 7. (Note 1)
N/A	-	EP	-	Exposed Pad. The thermally exposed pad on package bottom (see case drawing) must be attached to a heat-sinking conduit.

1. In the differential configuration when the input termination pins (VTDx , $\overline{\text{VTDx}}$, VTSEL) are connected to a common termination voltage, and if no signal is applied then the device will be susceptible to self-oscillation.
2. All V_{CC} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.
3. When an output level of 400 mV is desired and $V_{CC} - V_{EE} > 3.0 \text{ V}$, 2 k Ω resistor should be connected from OLS pin to V_{EE} .

Table 2. OUTPUT LEVEL SELECT OLS

OLS	Q/Q VPP	OLS Sensitivity
V_{CC}	800 mV	OLS - 75 mV
$V_{CC} - 0.4 \text{ V}$	200 mV	OLS $\pm 150 \text{ mV}$
$V_{CC} - 0.8 \text{ V}$	600 mV	OLS $\pm 100 \text{ mV}$
$V_{CC} - 1.2 \text{ V}$	0	OLS $\pm 75 \text{ mV}$
V_{EE} (Note 4)	400 mV	OLS $\pm 100 \text{ mV}$
Float	600 mV	N/A

4. When an output level of 400 mV is desired and $V_{CC} - V_{EE} > 3.0 \text{ V}$, 2.0 k Ω resistor should be connected from OLS to V_{EE} .

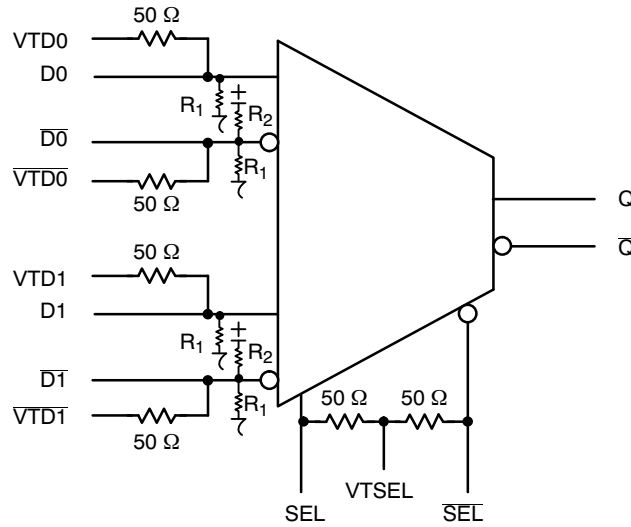


Figure 3. Logic Diagram

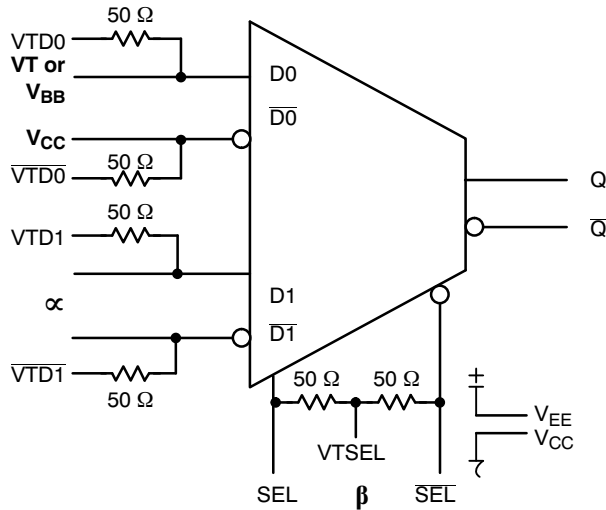


Figure 4. Configuration for AND/NAND Function

Table 3. AND/NAND TRUTH TABLE (Note 5)

	α	β	$\alpha * \beta$
D0	D1	SEL	Q
0	0	0	0
0	0	1	0
0	1	0	0
0	1	1	1

5. $\bar{D0}$, $\bar{D1}$, $\bar{SEL}$ are inverse of D0, D1, SEL unless specified otherwise.

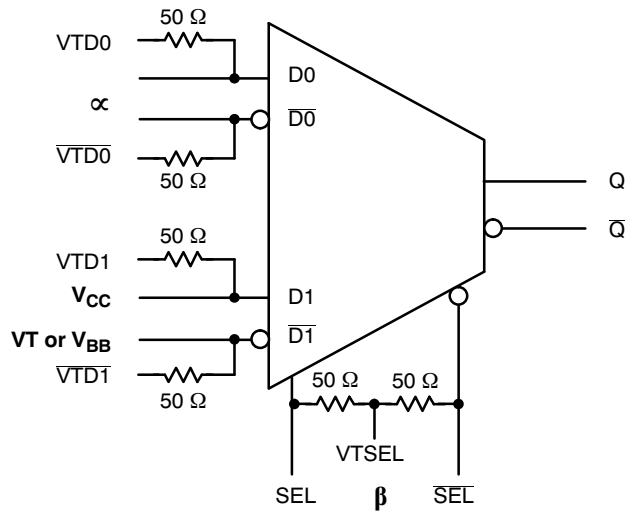


Figure 5. Configuration for OR/NOR Function

Table 4. OR/NOR TRUTH TABLE**

α		β	α or β
D0	D1	SEL	Q
0	1	0	0
0	1	1	1
1	1	0	1
1	1	1	1

** D0, D1, SEL are inverse of D0, D1, SEL unless specified otherwise.

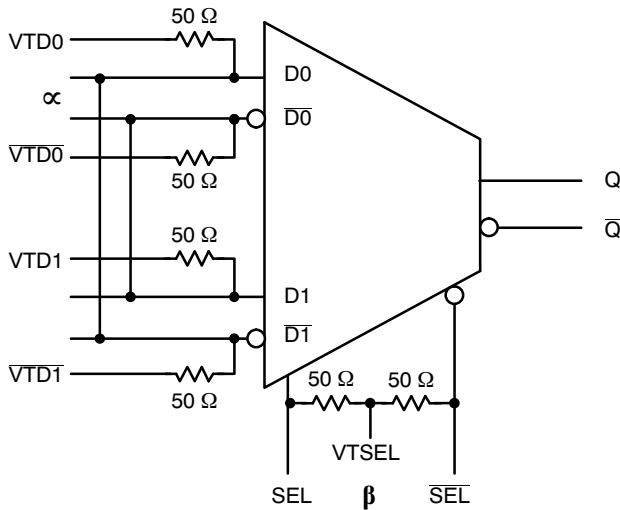


Figure 6. Configuration for XOR/XNOR Function

Table 5. XOR/XNOR TRUTH TABLE**

α		β	α XOR β
D0	D1	SEL	Q
0	1	0	0
0	1	1	1
1	0	0	1
1	0	1	0

** D0, D1, SEL are inverse of D0, D1, SEL unless specified otherwise.

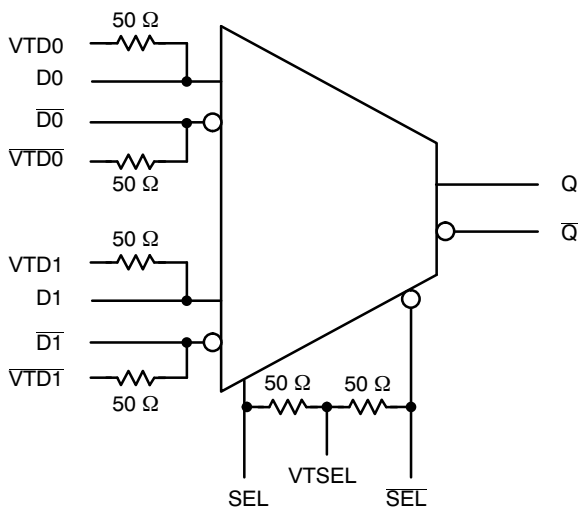


Figure 7. Configuration for 2:1 MUX Function

Table 6. 2:1 MUX TRUTH TABLE**

SEL	Q
1	D1
0	D0

** D0, D1, SEL are inverse of D0, D1, SEL unless specified otherwise.

Table 7. Interfacing Options

INTERFACING OPTIONS	CONNECTIONS
CML	Connect VTD0, VTD1, VTSEL and $\overline{\text{VTD0}}$, $\overline{\text{VTD1}}$ to V_{CC}
LVDS	Connect VTD0, VTD1, $\overline{\text{VTD0}}$ and $\overline{\text{VTD1}}$ together. Leave VTSEL open.
AC-COUPLED	Bias VTD0, VTD1, VTSEL and $\overline{\text{VTD0}}$, $\overline{\text{VTD1}}$ Inputs within (VIHCMR) Common Mode Range
RSECL, PECL, NECL	Standard ECL Termination Techniques
LVTTTL, LVCMOS	An external voltage should be applied to the unused complementary differential input. Nominal voltage 1.5 V for LVTTTL and $V_{CC}/2$ for LVCMOS inputs.

Table 8. ATTRIBUTES

Characteristics	Value	
Internal Input Pulldown Resistors (R_1)	75 k Ω	
Internal Input Pullup Resistor (R_2)	37.5 k Ω	
ESD Protection	Human Body Model Machine Model Charged Device Model	> 1 KV > 50 V > 4 KV
Moisture Sensitivity (Note 6)	Pb Pkg	Pb-Free Pkg
FCBGA-16, FCLGA-16 16-QFN	Level 3 Level 1	Level 3 Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	364	
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test		

6. For additional information, see Application Note AND8003/D.

Table 9. MAXIMUM RATINGS (Note 7)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V_{CC}	Positive Power Supply	$V_{EE} = 0 \text{ V}$		3.6	V
V_{EE}	Negative Power Supply	$V_{CC} = 0 \text{ V}$		-3.6	V
V_I	Positive Input Negative Input	$V_{EE} = 0 \text{ V}$ $V_{CC} = 0 \text{ V}$	$V_I \leq V_{CC}$ $V_I \geq V_{EE}$	3.6 -3.6	V V
V_{INPP}	Differential Input Voltage $ D_n - \overline{D_n} $	$V_{CC} - V_{EE} \geq 2.8 \text{ V}$ $V_{CC} - V_{EE} < 2.8 \text{ V}$		2.8 $ V_{CC} - V_{EE} $	V V
I_{IN}	Input Current Through R_T (50 Ω Resistor)	Static Surge		45 80	mA mA
I_{out}	Output Current	Continuous Surge		25 50	mA mA
T_A	Operating Temperature Range	16-FCBGA, FCLGA 16-QFN		-40 to +70 -40 to +85	$^{\circ}\text{C}$ $^{\circ}\text{C}$
T_{stg}	Storage Temperature Range			-65 to +150	$^{\circ}\text{C}$
θ_{JA}	Thermal Resistance (Junction-to-Ambient) (Note 8)	0 lfpm 500 lfpm 0 lfpm 500 lfpm	16 FCBGA, FCLGA 16 FCBGA, FCLGA 16 QFN 16 QFN	108 86 41.6 35.2	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
θ_{JC}	Thermal Resistance (Junction-to-Case)	2S2P (Note 8) 2S2P (Note 9)	16 FCBGA, FCLGA 16 QFN	5.0 4.0	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
T_{sol}	Wave Solder Pb (BGA) Pb-Free	< 15 sec < 3 sec @ 260 $^{\circ}\text{C}$		225 265	$^{\circ}\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

7. Maximum Ratings are those values beyond which device damage may occur.

8. JEDEC standard multilayer board - 2S2P (2 signal, 2 power).

9. JEDEC standard multilayer board - 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

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Table 10. DC CHARACTERISTICS, INPUT WITH PECL OUTPUT $V_{CC} = 2.5\text{ V}$; $V_{EE} = 0\text{ V}$ (Note 10)

Symbol	Characteristic	-40°C			25°C			70°C(LGA)/85°C(QFN)**			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Negative Power Supply Current	23	30	39	23	30	39	23	30	39	mA
V_{OH}	Output HIGH Voltage (Note 11)	1460	1510	1560	1490	1540	1590	1515	1565	1615	mV
V_{OL}	Output LOW Voltage (Note 11) (OLS = V_{CC}) (OLS = $V_{CC} - 0.4\text{ V}$) (OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT) (OLS = $V_{CC} - 1.2\text{ V}$) (OLS = V_{EE})	555 1235 775 1455 1005	705 1295 895 1505 1095	855 1385 1015 1585 1215	595 1270 810 1490 1040	745 1330 930 1540 1130	895 1420 1050 1620 1250	625 1295 840 1510 1065	775 1355 960 1560 1155	925 1445 1080 1640 1275	mV
V_{OUTPP}	Output Voltage Amplitude (OLS = V_{CC}) (OLS = $V_{CC} - 0.4\text{ V}$) (OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT) (OLS = $V_{CC} - 1.2\text{ V}$) (OLS = V_{EE})	670 125 510 0 325	800 215 615 5 415		660 120 505 0 320	795 210 610 0 410		655 120 500 0 320	790 210 605 5 410		mV
V_{IH}	Input HIGH Voltage (Single-Ended) (Note 13) D, $\bar{D}$	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	mV
V_{IL}	Input LOW Voltage (Single-Ended) (Note 14) D, $\bar{D}$	V_{EE}	$V_{CC} - 1400^*$	$V_{IH} - 150$	V_{EE}	$V_{CC} - 1400^*$	$V_{IH} - 150$	V_{EE}	$V_{CC} - 1400^*$	$V_{IH} - 150$	mV
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 12)	1.2		2.5	1.2		2.5	1.2		2.5	V
R_{TIN}	Internal Input Termination Resistor	45	50	55	45	50	55	45	50	55	Ω
I_{IH}	Input HIGH Current (@ V_{IH}) D, $\bar{D}$ SEL		30 5	100 50		30 5	100 50		30 5	100 50	μA
I_{IL}	Input LOW Current (@ V_{IL}) D, $\bar{D}$ SEL		20 5	100 50		20 5	100 50		20 5	100 50	μA

NOTE: GigaComm circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established.

The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfm is maintained.

10. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.125 V to -0.965 V.

11. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$.

12. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

13. V_{IH} cannot exceed V_{CC} .

14. V_{IL} always $\geq V_{EE}$.

*Typicals used for testing purposes.

**The device packaged in FCLGA-16 have maximum ambient temperature specification of 70°C and devices packaged in QFN-16 have maximum ambient temperature specification of 85°C.

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Table 11. DC CHARACTERISTICS, INPUT WITH PECL OUTPUT $V_{CC} = 3.3\text{ V}$; $V_{EE} = 0\text{ V}$ (Note 15)

Symbol	Characteristic	-40°C			25°C			70°C(LGA)/85°C(QFN)***			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Negative Power Supply Current	23	30	39	23	30	39	23	30	39	mA
V_{OH}	Output HIGH Voltage (Note 16)	2260	2310	2360	2290	2340	2390	2315	2365	2415	mV
V_{OL}	Output LOW Voltage (Note 16)										mV
	(OLS = V_{CC})	1320	1470	1620	1360	1510	1660	1390	1540	1690	
	(OLS = $V_{CC} - 0.4\text{ V}$)	2030	2090	2180	2065	2125	2215	2090	2150	2240	
	(OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT)	1550	1670	1790	1585	1705	1825	1615	1735	1855	
	(OLS = $V_{CC} - 1.2\text{ V}$)	2260	2310	2390	2290	2340	2420	2315	2365	2445	
	** (OLS = V_{EE})	1785	1875	1995	1820	1910	2030	1850	1940	2060	
V_{OUTPP}	Output Amplitude Voltage										mV
	(OLS = V_{CC})	705	815		695	805		690	800		
	(OLS = $V_{CC} - 0.4\text{ V}$)	130	220		125	215		125	215		
	(OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT)	535	640		530	635		525	630		
	(OLS = $V_{CC} - 1.2\text{ V}$)	0	0		0	0		0	0		
	** (OLS = V_{EE})	345	435		340	430		335	425		
V_{IH}	Input HIGH Voltage (Single-Ended) (Note 18) D, $\bar{D}$	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	mV
V_{IL}	Input LOW Voltage (Single-Ended) (Note 19) D, $\bar{D}$	$V_{IH} - 2600$	$V_{CC} - 1400^*$	$V_{IH} - 150$	$V_{IH} - 2600$	$V_{CC} - 1400^*$	$V_{IH} - 150$	$V_{IH} - 2600$	$V_{CC} - 1400^*$	$V_{IH} - 150$	mV
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 17)	1.2		3.3	1.2		3.3	1.2		3.3	V
R_{TIN}	Internal Input Termination Resistor	45	50	55	45	50	55	45	50	55	Ω
I_{IH}	Input HIGH Current (@ V_{IH}) D, $\bar{D}$ SEL		30 5	100 50		30 5	100 50		30 5	100 50	μA
I_{IL}	Input LOW Current (@ V_{IL}) D, $\bar{D}$ SEL		20 5	100 50		20 5	100 50		20 5	100 50	μA

NOTE: GigaComm circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established.

The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfm is maintained.

15. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.925 V to -0.165 V.

16. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$.

17. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

18. V_{IH} cannot exceed V_{CC} .

19. V_{IL} always $\geq V_{EE}$.

*Typicals used for testing purposes.

**When an output level of 400 mV is desired and $V_{CC} - V_{EE} > 3.0\text{ V}$, a 2 k Ω resistor should be connected from OLS to V_{EE} .

***The device packaged in FCLGA-16 have maximum ambient temperature specification of 70°C and devices packaged in QFN-16 have maximum ambient temperature specification of 85°C.

Table 12. DC CHARACTERISTICS, NECL INPUT WITH NECL OUTPUT $V_{CC} = 0\text{ V}$; $V_{EE} = -3.465\text{ V}$ to -2.375 V (Note 20)

Symbol	Characteristic	-40°C			25°C			70°C(LGA)/85°C(QFN)***			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Negative Power Supply Current	23	30	39	23	30	39	23	30	39	mA
V_{OH}	Output HIGH Voltage (Note 21)	-1040	-990	-940	-1010	-960	-910	-985	-935	-885	mV
V_{OL}	Output LOW Voltage (Note 21) $-3.465\text{ V} \leq V_{EE} \leq -3.0\text{ V}$ (OLS = V_{CC}) (OLS = $V_{CC} - 0.4\text{ V}$) (OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT) (OLS = $V_{CC} - 1.2\text{ V}$) ** (OLS = V_{EE}) $-3.0\text{ V} < V_{EE} \leq -2.375\text{ V}$ (OLS = V_{CC}) (OLS = $V_{CC} - 0.4\text{ V}$) (OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT) (OLS = $V_{CC} - 1.2\text{ V}$) (OLS = V_{EE})	-1980 -1270 -1750 -1040 -1515 -1945 -1265 -1725 -1045 -1495	-1830 -1210 -1630 -990 -1425 -1795 -1205 -1605 -995 -1405	-1680 -1120 -1510 -910 -1305 -1645 -1115 -1485 -915 -1285	-1940 -1235 -1510 -1010 -1480 -1905 -1230 -1690 -1010 -1460	-1790 -1175 -1595 -960 -1390 -1755 -1170 -1570 -960 -1370	-1640 -1085 -1475 -880 -1270 -1605 -1080 -1450 -880 -1250	-1910 -1210 -1685 -985 -1450 -1875 -1205 -1660 -990 -1435	-1760 -1150 -1565 -935 -1360 -1725 -1145 -1540 -940 -1345	-1610 -1060 -1445 -855 -1240 -1575 -1055 -1420 -860 -1225	mV
V_{OUTPP}	Output Voltage Amplitude $-3.465\text{ V} \leq V_{EE} \leq -3.0\text{ V}$ (OLS = V_{CC}) (OLS = $V_{CC} - 0.4\text{ V}$) (OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT) (OLS = $V_{CC} - 1.2\text{ V}$) ** (OLS = V_{EE}) $-3.0\text{ V} < V_{EE} \leq -2.375\text{ V}$ (OLS = V_{CC}) (OLS = $V_{CC} - 0.4\text{ V}$) (OLS = $V_{CC} - 0.8\text{ V}$, OLS = FLOAT) (OLS = $V_{CC} - 1.2\text{ V}$) (OLS = V_{EE})	705 130 535 0 345 670 125 510 0 325	815 220 640 0 435 800 215 615 5 415		695 125 530 0 340 660 120 505 0 320	805 215 635 0 430 795 210 610 0 410		690 125 525 0 335 655 120 500 0 320	800 215 630 0 425 790 210 605 5 410		mV
V_{IH}	Input HIGH Voltage (Single-Ended) (Note 23) D, $\bar{D}$	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	$V_{EE} + 1275$	$V_{CC} - 1000^*$	V_{CC}	mV
V_{IL}	Input LOW Voltage (Single-Ended) (Note 24) D, $\bar{D}$	$V_{IH} - 2600$	$V_{CC} - 1400^*$	$V_{IH} - 150$	$V_{IH} - 2600$	$V_{CC} - 1400^*$	$V_{IH} - 150$	$V_{IH} - 2600$	$V_{CC} - 1400^*$	$V_{IH} - 150$	mV
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 22)	$V_{EE} + 1.2$		0.0	$V_{EE} + 1.2$		0.0	$V_{EE} + 1.2$		0.0	V
R_{TIN}	Internal Input Termination Resistor	45	50	55	45	50	55	45	50	55	Ω
I_{IH}	Input HIGH Current (@ V_{IH}) D, $\bar{D}$ SEL		30 5	100 50		30 5	100 50		30 5	100 50	μA
I_{IL}	Input LOW Current (@ V_{IL}) D, $\bar{D}$ SEL		20 5	100 50		20 5	100 50		20 5	100 50	μA

NOTE: GigaComm circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established.

The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

20. Input and output parameters vary 1:1 with V_{CC} .

21. All loading with $50\ \Omega$ to $V_{CC} - 2.0\text{ V}$.

22. V_{IHCMR} min varies 1:1 with V_{EE} . V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

23. V_{IH} cannot exceed V_{CC} .

24. V_{IL} always $\geq V_{EE}$.

*Typicals used for testing purposes.

**When an output level of 400 mV is desired and $V_{CC} - V_{EE} > 3.0\text{ V}$, a $2\text{ k}\Omega$ resistor should be connected from OLS to V_{EE} .

***The device packaged in FCLGA-16 have maximum ambient temperature specification of 70°C and devices packaged in QFN-16 have maximum ambient temperature specification of 85°C.

Table 13. AC CHARACTERISTICS for FCLGA-16

$V_{CC} = 0\text{ V}$; $V_{EE} = -3.465\text{ V}$ to -2.375 V or $V_{CC} = 2.375\text{ V}$ to 3.465 V ; $V_{EE} = 0\text{ V}$

Symbol	Characteristic	-40°C			25°C			70°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$f_{\max}$	Maximum Frequency (See Figure 8) (Note 25)	7	8		7	8		7	8		GHz
V_{OUTPP}	Output Voltage Amplitude (OLS = V_{CC}) $f_{\text{in}} \leq 7\text{ GHz}$	550	740		500	720		450	700		mV
t_{PLH} , t_{PHL}	Propagation Delay to Output Differential D/SEL $\rightarrow$ Q	110	160	210	115	165	215	120	170	220	ps
t_{SKEW}	Duty Cycle Skew (Note 26)		5	15		5	15		5	15	ps
t_{SKEW}	Channel Skew Q $\rightarrow$ D/SEL		5	20		5	20		5	20	ps
t_{JITTER}	RMS Random Clock Jitter (See Figure 8) (Note 25) $f_{\text{in}} \leq 7\text{ GHz}$ Peak-to-Peak Data Dependent Jitter $f_{\text{in}} \leq 7\text{ Gb/s}$		0.5 12	1.5		0.5 12	1.5		0.5 12	1.5	ps
V_{INPP}	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 27)	75		2600	75		2600	75		2600	mV
t_r t_f	Output Rise/Fall Times (20% – 80%) (Q, $\bar{Q}$) @ 1 GHz	20	40	65	20	40	65	20	40	65	ps

25. Measured using a 500 mV source, 50% duty cycle clock source. All loading with $50\ \Omega$ to $V_{CC} - 2.0\text{ V}$. Input edge rates 40 ps (20% – 80%).

26. $t_{\text{SKEW}} = |t_{\text{PLH}} - t_{\text{PHL}}|$ for a nominal 50% differential clock input waveform. See Figure 12.

27. V_{INPP} (max) cannot exceed $V_{CC} - V_{EE}$.

Table 14. AC CHARACTERISTICS for QFN-16

$V_{CC} = 0\text{ V}$; $V_{EE} = -3.465\text{ V}$ to -2.375 V or $V_{CC} = 2.375\text{ V}$ to 3.465 V ; $V_{EE} = 0\text{ V}$

Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$f_{\max}$	Maximum Frequency (See Figure 8) (Note 28)	7	8		7	8		7	8		GHz
V_{OUTPP}	Output Voltage Amplitude $f_{\text{in}} \leq 7\text{ GHz}$ (OLS = V_{CC}) $f_{\text{in}} = 8\text{ GHz}$	590 270	730 440		470 230	720 420		540 180	700 390		mV mV
t_{PLH} , t_{PHL}	Propagation Delay to Output Differential D/SEL $\rightarrow$ Q	110	160	210	115	165	215	120	170	220	ps
t_{SKEW}	Duty Cycle Skew (Note 29)		5	15		5	15		5	15	ps
t_{SKEW}	Channel Skew Q $\rightarrow$ D/SEL		5	20		5	20		5	20	ps
t_{JITTER}	RMS Random Clock Jitter (See Figure 8) (Note 31) $f_{\text{in}} \leq 7\text{ GHz}$ Peak-to-Peak Data Dependent Jitter (Note 32) $f_{\text{in}} \leq 7\text{ Gb/s}$		0.5 12	1.5		0.5 12	1.5		0.5 12	1.5	ps
V_{INPP}	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 30)	75		2600	75		2600	75		2600	mV
t_r t_f	Output Rise/Fall Times (20% – 80%) (Q, $\bar{Q}$) @ 1 GHz	30 17	45 35	60 65	30 17	45 35	60 65	30 17	45 35	60 65	ps

28. Measured using a 500 mV source, 50% duty cycle clock source. All loading with $50\ \Omega$ to $V_{CC} - 2.0\text{ V}$. Input edge rates 40 ps (20% – 80%).

29. $t_{\text{SKEW}} = |t_{\text{PLH}} - t_{\text{PHL}}|$ for a nominal 50% differential clock input waveform. See Figure 12.

30. V_{INPP} (max) cannot exceed $V_{CC} - V_{EE}$.

31. Additive RMS jitter with 50% duty cycle clock signal at 7 GHz.

32. Additive Peak-to-Peak data dependent jitter with NRZ PRBS $2^{31}-1$ data rate at 7 Gb/s.

NBSG86A

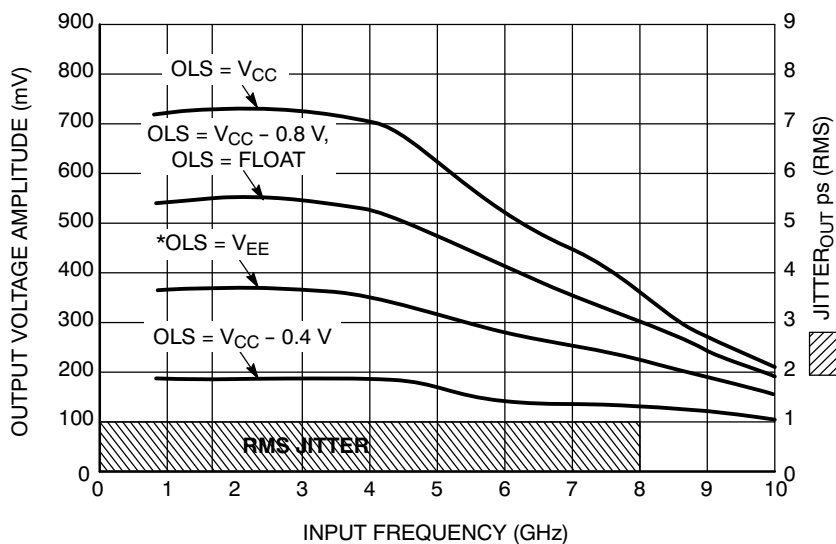


Figure 8. Output Voltage Amplitude (V_{OUTPP}) / RMS Jitter vs. Input Frequency (f_{in}) for 2:1 MUX Mode ($V_{CC} - V_{EE} = 2.5\text{ V}$ @ 25°C ; Repetitive 1010 Input Data Pattern)

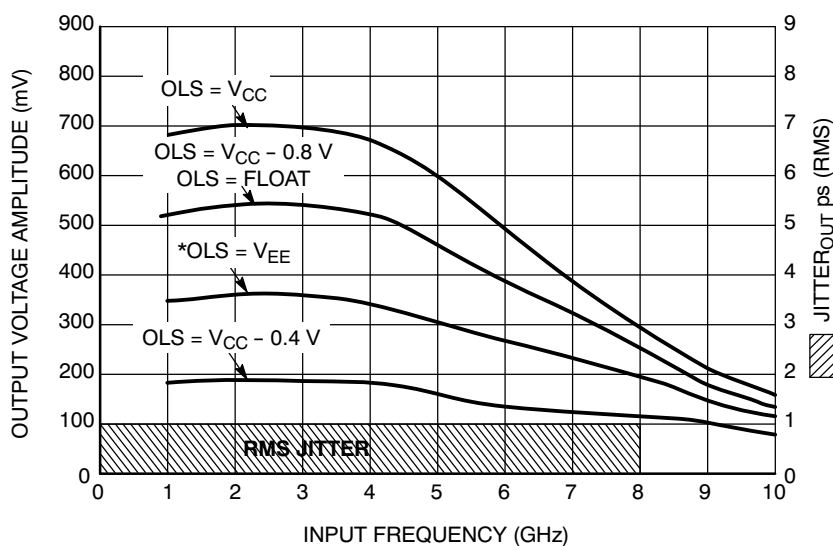


Figure 9. Output Voltage Amplitude (V_{OUTPP}) / RMS Jitter vs. Input Frequency (f_{in}) for 2:1 MUX Mode ($V_{CC} - V_{EE} = 3.3\text{ V}$ @ 25°C ; Repetitive 1010 Input Data Pattern)

*When an output level of 400 mV is desired and $V_{CC} - V_{EE} > 3.0\text{ V}$, a $2\text{ k}\Omega$ resistor should be connected from OLS to V_{EE} .

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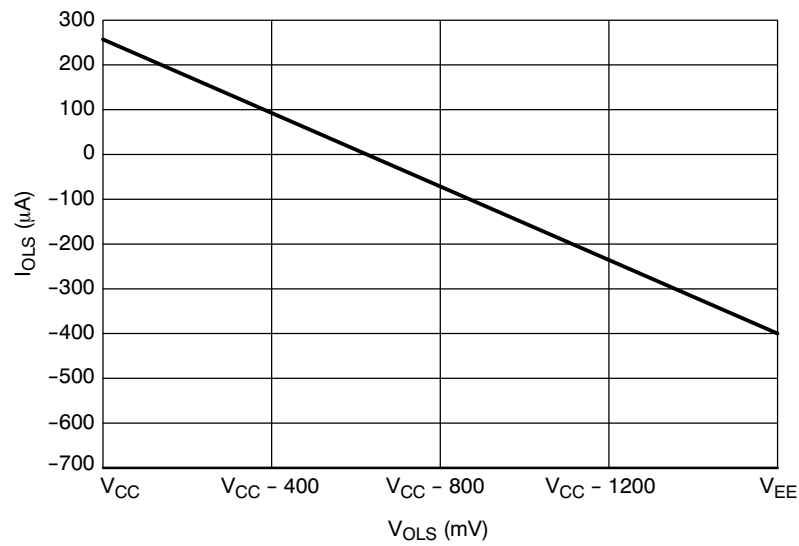


Figure 10. Typical OLS Input Current vs. OLS Input Voltage
 $(V_{CC} - V_{EE} = 3.3 \text{ V @ } 25^{\circ}\text{C})$

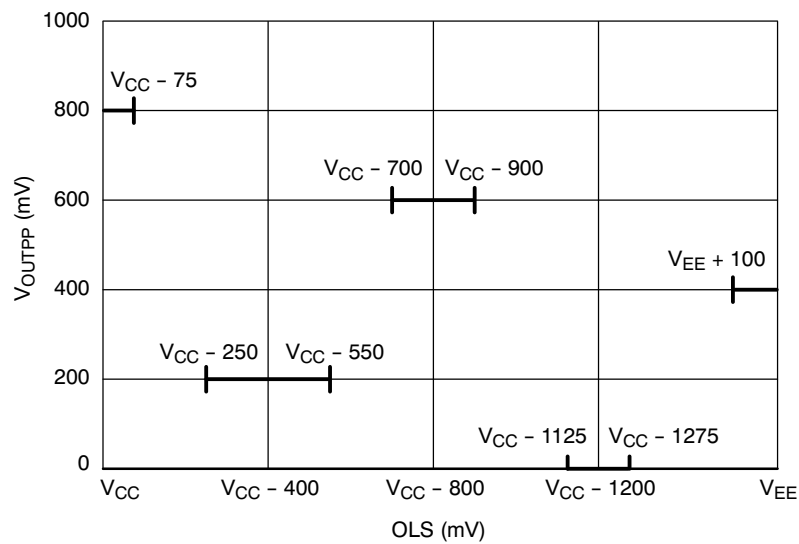


Figure 11. OLS Operating Area

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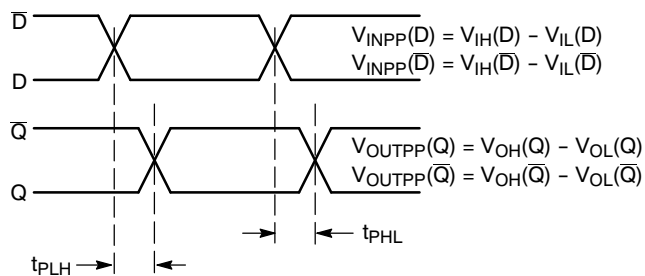


Figure 12. AC Reference Measurement

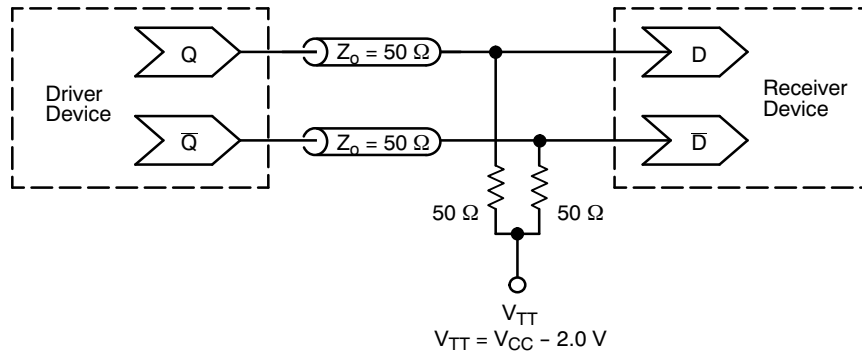


Figure 13. Typical Termination for Output Driver and Device Evaluation
(See Application Note AND8020/D – Termination of ECL Logic Devices.)

ORDERING INFORMATION

Device	Package Type	Shipping [†]
NBSG86ABA	4x4 mm FCBGA-16	100 Units / Tray (Contact Sales Representative)
NBSG86ABAR2	4x4 mm FCBGA-16	100 / Tape & Reel (Contact Sales Representative)
NBSG86AMAG	FCLGA-16, 4x4 mm (Pb-Free)	100 Units / Tray (Contact Sales Representative)
NBSG86AMAHTBG	FCLGA-16, 4x4 mm (Pb-Free)	100 / Tape & Reel
NBSG86AMN	3x3 mm QFN-16	123 Units / Rail
NBSG86AMNG	3x3 mm QFN-16 (Pb-Free)	123 Units / Rail
NBSG86AMNR2G	3x3 mm QFN-16 (Pb-Free)	3000 / Tape & Reel

Board	Description
NBSG86ABAEVB	NBSG86ABA Evaluation Board

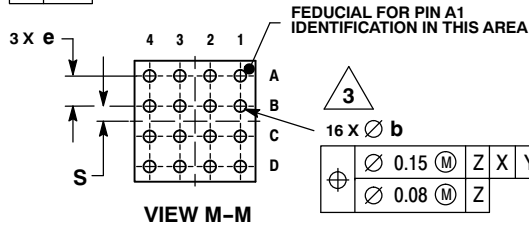
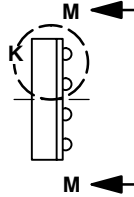
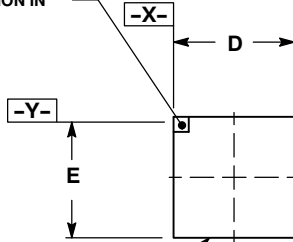
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NBSG86A

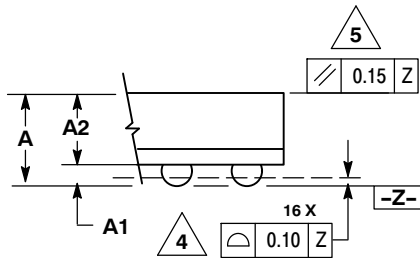
PACKAGE DIMENSIONS

FCBGA-16
BA SUFFIX
 PLASTIC 4 X 4 (mm) BGA FLIP CHIP PACKAGE
 CASE 489-01
 ISSUE O

LASER MARK FOR PIN 1
 IDENTIFICATION IN
 THIS AREA



VIEW M-M



DETAIL K
 ROTATED 90° CLOCKWISE

NOTES:

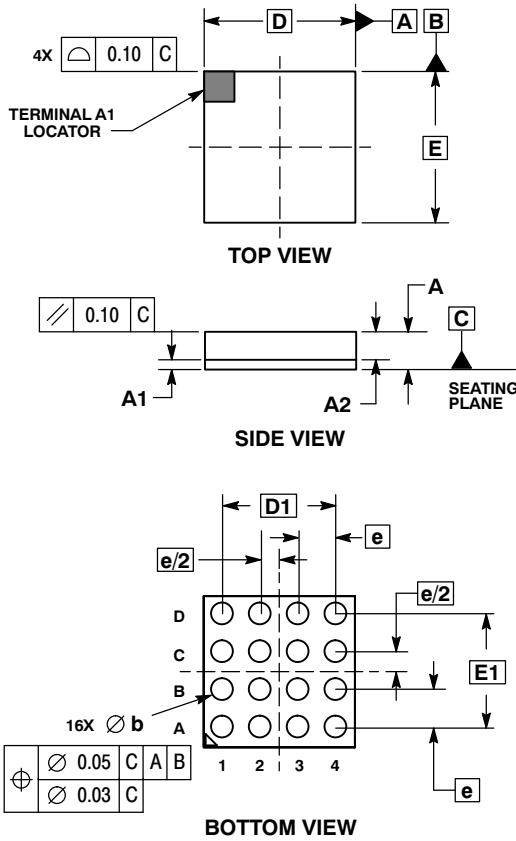
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO DATUM PLANE Z.
4. DATUM Z (SEATING PLANE) IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

MILLIMETERS		
DIM	MIN	MAX
A	1.40	MAX
A1	0.25	0.35
A2	1.20	REF
b	0.30	0.50
D	4.00	BSC
E	4.00	BSC
e	1.00	BSC
S	0.50	BSC

NBSG86A

PACKAGE DIMENSIONS

16 PIN LGA 4x4, 1.0P
CASE 526AB-01
ISSUE C

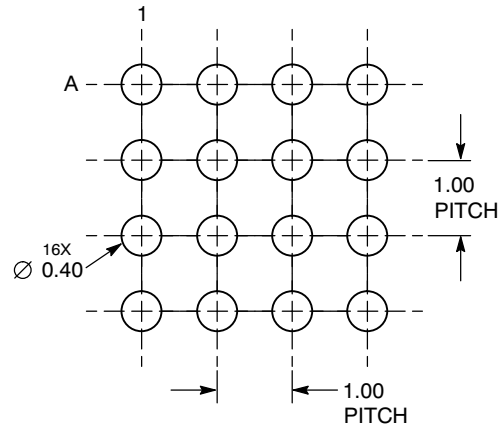


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.

DIM	MILLIMETERS		
	MIN	TYP	MAX
A	0.89	0.96	1.03
A1	0.22	0.26	0.30
A2	0.67	0.70	0.73
b	0.30	0.40	0.50
D	4.00 BSC		
D1	3.00 BSC		
E	4.00 BSC		
E1	3.00 BSC		
e	1.00 BSC		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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